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Characteristic	Symbol	Value	Units		
Drain-Source Voltage			$V_{DSS}$	-60	V
Gate-Source Voltage			$V_{GSS}$	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ΙD	-14 -10	А
Maximum Body Diode Forward Current (Note 6)			Is	4.1	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	25	Α

#### Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	·	Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	р	1.7	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	$P_{D}$	1.0	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	Б	76	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	33	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	$P_{D}$	2.7	W
Total Fower Dissipation (Note o)	$T_A = +70^{\circ}C$	FD	1.5	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	Б	50	°C/W
Thermal Resistance, Junction to Ambient (Note o)	t<10s	$R_{\theta JA}$	24	
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	$P_{D}$	40	W
Total Fower Dissipation (Note o)	$T_{C} = +100^{\circ}C$	FD	16	
Thermal Resistance, Junction to Case (Note 6)	Steady state	$R_{\theta JC}$	3.1	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			-1	μΑ	$V_{DS} = -48V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>			100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.2		-2.7	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	В		60	110	mΩ	$V_{GS} = -10V, I_D = -12A$	
Static Diain-Source On-Nesistance	R <sub>DS</sub> (ON)		80	140	11122	$V_{GS} = -4.5V, I_D = -8A$	
Forward Transfer Admittance	Y <sub>fs</sub>		15	_	S	$V_{DS} = -5V$ , $I_{D} = -12A$	
Diode Forward Voltage	$V_{SD}$		-0.7	-1.0	V	$V_{GS} = 0V$ , $I_S = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>		984.7	_		V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss		58	_	pF		
Reverse Transfer Capacitance	Crss		45.5	_			
Gate Resistance	$R_{G}$		12.9	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		8.1	_		V <sub>DS</sub> = -30V, I <sub>D</sub> = -12A	
Total Gate Charge (V <sub>GS</sub> = -10V)	$Q_g$		17.1	_	nC		
Gate-Source Charge	$Q_{gs}$		3.2	_	110		
Gate-Drain Charge	$Q_{gd}$		3.9	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	5.9	_		$V_{GS} = -10V, V_{DS} = -30V, R_{GEN} = 3\Omega,$ $R_L = 2.5\Omega$	
Turn-On Rise Time	tr	_	21.2	_	ns		
Turn-Off Delay Time	t <sub>D(off)</sub>	_	30.9	_	118		
Turn-Off Fall Time	t <sub>f</sub>		39.1	_			
Body Diode Reverse Recovery Time	t <sub>rr</sub>		19.9	_	ns	$I_S = -12A$ , $dI/dt = 100A/\mu s$	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>		1.7	_	nC	$I_S = -12A$ , $dI/dt = 100A/\mu s$	

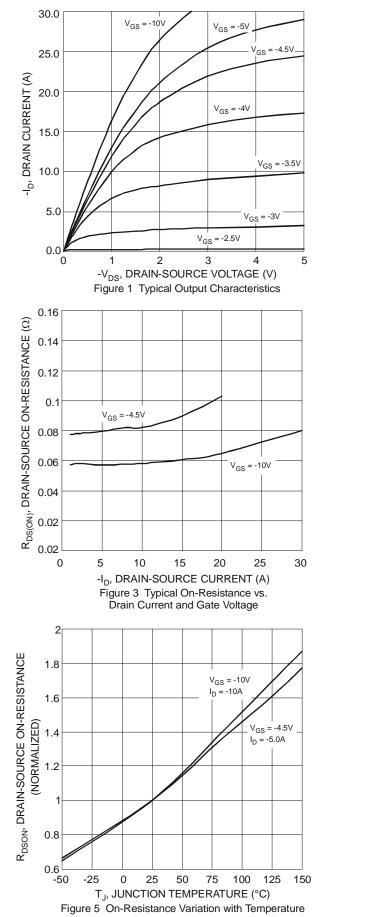
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

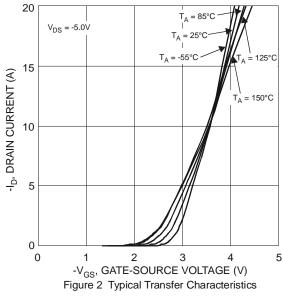
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

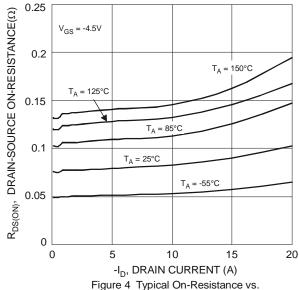
7. Short duration pulse test used to minimize self-heating effect

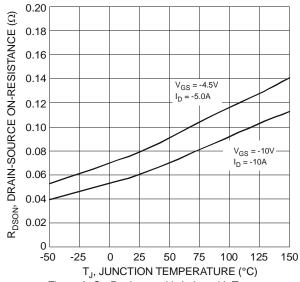
8. Guaranteed by design. Not subject to production testing











Drain Current and Temperature



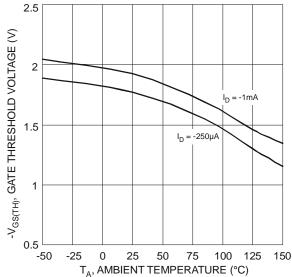
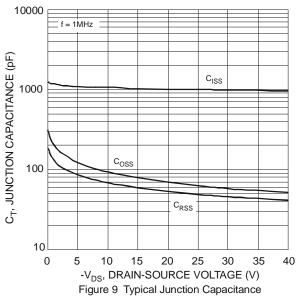


Figure 7 Gate Threshold Variation vs. Ambient Temperature



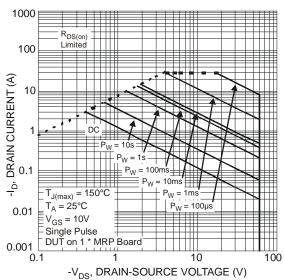
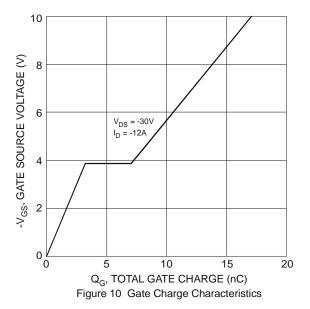
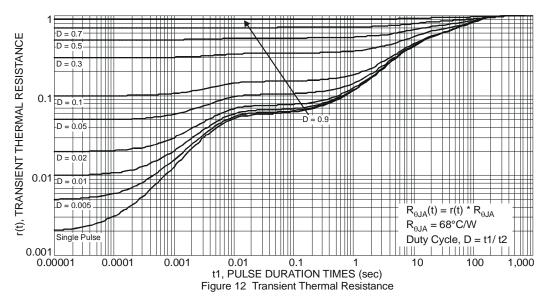


Figure 11 SOA, Safe Operation Area

30 25 -I<sub>S</sub>, SOURCE CURRENT (A) 20 T<sub>A</sub> = 85°C 15  $T_A^{\circ} = -55^{\circ}C$ 10 T<sub>A</sub> = 150°C = 25°C 5 0 1.2 1.4 1.6 0.6 8.0 -V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Figure 8 Diode Forward Voltage vs. Current

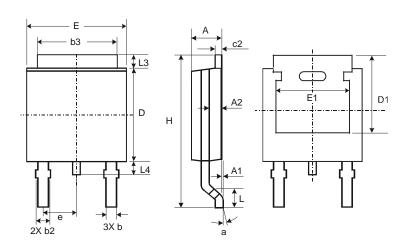






## **Package Outline Dimensions**

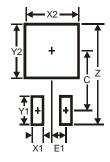
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A1</b>	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	_	_		
е	_	_	2.286		
Е	6.45	6.70	6.58		
E1	4.32	_	_		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	11.6		
X1	1.5		
X2	7.0		
Y1	2.5		
Y2	7.0		
С	6.9		
E1	2.3		



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